TLE7279-2

Low Dropout Voltage Regulator

Automotive Power



Never stop thinking



Low Dropout Voltage Regulator

TLE7279-2GV50



1 Overview

Features

- Output voltage 5 V, 3.3 V or 2.6 V
- Output voltage tolerance ±2%
- Output current up to 180 mA
- Ultra low quiescent current consumption < 36 μA
- Enable function
- · Very low dropout voltage
- Reset with adjustable power-on delay
- Input Voltage Sense (Early Warning)
- Output protected against short circuit
- Wide operation range: up to 45 V
- Wide temperature range: -40 °C to 150 °C
- Overtemperature protection
- Overload protection
- Green Product (RoHS compliant)
- AEC Qualified



PG-SSOP-14 Exposed Pad

Description

The TLE7279-2 is a monolithic integrated voltage regulator with early warning and reset dedicated for microcontroller supplies under harsh automotive environment conditions.

Due to its ultra low quiescent current the TLE7279-2 is perfectly suited for applications permanently connected to battery. In addition the regulator can be shut down via the Enable input causing the current consumption to drop below 3 μ A. The TLE7279-2 is equipped with an output current limitation and an overtemperature shutdown protecting the device against overload, short circuit and overtemperature. It operates in the wide junction temperature range from -40 °C to 150 °C.

Туре	Package	Marking
TLE7279-2GV50	PG-DSO-14	TLE7279-2GV50
TLE7279-2GV33	PG-DSO-14	TLE7279-2GV33
TLE7279-2GV26	PG-DSO-14	TLE7279-2GV26
TLE7279-2EV50	PG-SSOP-14 Exposed Pad	7279 V50



Pin Configuration

2 Pin Configuration

2.1 Pin Assignment (PG-DSO-14)



Figure 1 Pin Configuration

2.2 Pin Definitions and Functions (PG-DSO-14)

Pin	Symbol	Function
1	RO	Reset Output
		TLE7279-2GV33, TLE7279-2GV26: open drain output;
		TLE7279-2GV50: integrated 20 k Ω pull-up resistor;
		leave open if Reset is not needed
2-5,	GND	Ground
10-12		connect pin 2 and 3 to GND;
		connect pin 4-5, 10-12 to PCB heat sink area with GND potential
8	SI	Sense Input
		connect to Q if not needed
6	RM	Reset Mode
		power-on reset delay time selection: set to LOW for fast timing, to HIGH for slow
		timing;
		see reset timing definitions in "Electrical Characteristics" on Page 10;
		connect to Q or GND
7	SO	Sense Output
		TLE7279-2GV33, TLE7279-2GV26: open-drain output;
		TLE7279-2GV50: integrated 20 k Ω pull-up resistor;
_		keep open, if sense comparator not needed
9	Q	Output Voltage
		block to GND with a ceramic capacitor close to the IC terminals, respecting the
		values given for its capacitance and ESR in "Functional Range" on Page 7
13	I	Input Voltage
		block to ground directly at the IC with a 100 nF ceramic capacitor
14	EN	Enable Input
		low level disables the IC;
		integrated pull-down resistor to GND



Pin Configuration

2.3 Pin Assignment (PG-SSOP-14 Exposed Pad)



Figure 2 Pin Configuration

2.4 Pin Definitions and Functions (PG-SSOP-14 Exposed Pad)

Pin	Symbol	Function
1	RO	Reset Output integrated 20 k Ω pull-up resistor; leave open if Reset is not needed
2, 5	GND	Ground connect pin 2 and 5 to GND
3, 4, 10, 11, 12	n.c.	not connected leave open or connect to GND
6	RM	Reset Mode power-on reset delay time selection: set to LOW for fast timing, to HIGH for slow timing; see reset timing definitions in "Electrical Characteristics" on Page 10; connect to Q or GND
7	SO	Sense Output integrated 20 k Ω pull-up resistor; keep open, if sense comparator not needed
8	SI	Sense Input connect to Q if not needed
9	Q	Output Voltage block to GND with a ceramic capacitor close to the IC terminals, respecting the values given for its capacitance and ESR in "Functional Range" on Page 7
13	I	Input Voltage block to ground directly at the IC with a 100 nF ceramic capacitor
14	EN	Enable Input low level disables the IC; integrated pull-down resistor to GND
Pad	-	Exposed Pad connect to heatsink area; connect to GND on PCB



TLE7279-2

Block Diagram

3 Block Diagram



Figure 3 Block Diagram



4 General Product Characteristics

4.1 Absolute Maximum Ratings

Absolute Maximum Ratings ¹⁾

 $T_{\rm j}$ = -40 °C to +150 °C; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Lin	nit Values	Unit	Conditions
			Min.	Max.		
Input I,	Sense Input SI		-+		ŀ	
4.1.1	Voltage	$V_{\rm I}, V_{\rm SI}$	-0.3	45	V	-
Output	Q, Reset Output RO, Sense Out SO	I		I		-
4.1.2	Voltage	$V_{\rm Q}, V_{\rm RO}, V_{\rm SO}$	-0.3	5.5	V	permanent
4.1.3	Voltage	$V_{\rm Q}, V_{\rm RO}, V_{\rm SO}$	-0.3	6.2	V	$t < 10 \text{ s}^{2)}$
Enable	Input EN	I	4	I		
4.1.4	Voltage	$V_{\sf EN}$	-1	45	V	-
4.1.5	Current	I _{EN}	-1	1	mA	-
Reset M	lode RM			k		
4.1.6	Voltage	V_{RM}	-0.3	5.5	V	permanent
4.1.7	Voltage	V _{RM}	-0.3	6.2	V	$t < 10 \ s^{2}$
4.1.8	Current	I _{RM}	-5	5	mA	-
ESD Su	sceptibility	i	- t		E	
4.1.9	Human Body Model (HBM) ³⁾	Voltage	-	3	kV	-
4.1.10	Charge Device Model (CDM) ⁴⁾	Voltage	_	1.5	kV	-
Temper	atures	I				
4.1.11	Junction temperature	Tj	-40	150	°C	-
4.1.12	Storage temperature	T _{stg}	-50	150	°C	-
1) not si	ubject to production test, specified by desig			1	1	

1) not subject to production test, specified by design

2) exposure to these absolute maximum ratings for extended periods (t > 10 s) may affect device reliability

3) ESD HBM Test according to JEDEC JESD22-A114

4) ESD CDM Test according AEC/ESDA ESD-STM5.3.1-1999

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.



General Product Characteristics

4.2 Functional Range

Parameter	Symbol	Lir	nit Values	Unit	Conditions
		Min.	Max.		
Input voltage	V ₁	5.5	45	V	TLE7279-2GV50, TLE7279-2EV50
		4.2	45	V	TLE7279-2GV33
		4.5	45	V	TLE7279-2GV26
Output capacitor's requirements for	CQ	470	-	nF	_1)
Stability	$ESR(C_Q)$	-	3	Ω	_2)
Junction temperature	T_{i}	-40	150	°C	-
	Input voltage Output capacitor's requirements for Stability	Input voltage V_1 Output capacitor's requirements for Stability C_Q $ESR(C_Q)$	$\begin{array}{c c c c c c c } \hline & & & & & & & & & & & & & & & & & & $	$ \begin{array}{ c c c c } \hline \mbox{Min.} & \mbox{Max.} \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & & & & & \\ \hline \mbox{Input voltage} & &$	$ \begin{array}{ c c c c } \hline \textbf{Min.} & \textbf{Max.} \\ \hline \textbf{Min.} & \textbf{Max.} \\ \hline \textbf{Input voltage} & V_1 & 5.5 & 45 & V \\ \hline & 4.2 & 45 & V \\ \hline & 4.5 & 45 & V \\ \hline & 4.5 & 45 & V \\ \hline & 0 \text{utput capacitor's requirements for} \\ \hline \textbf{Stability} & \hline & C_{\text{Q}} & 470 & & \text{nF} \\ \hline & ESR(C_{\text{Q}}) & - & 3 & \Omega \\ \hline \end{array} $

1) the minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

2) relevant ESR value at f = 10 kHz

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

4.3 Thermal Resistance

Pos.	Parameter	Symbol		Limit Val	ues	Unit	Conditions
			Min.	Тур.	Max.		
Packag	ge PG-DSO-14	H	1		L		
4.3.1	Junction to Soldering Point ¹⁾	R _{thJSP}	-	30	-	K/W	measured to group of pins 3, 4, 5, 10, 11, 12
4.3.2	Junction to Ambient ¹⁾	R _{thJA}	_	53	_	K/W	2)
4.3.3			-	105	_	K/W	footprint only ³⁾
4.3.4	-		-	74	-	K/W	300 mm ² heatsink area on PCB ³⁾
4.3.5	_		-	65	-	K/W	600 mm ² heatsink area on PCB ³⁾
Packag	ge PG-SSOP-14 Exposed Pad			I	I		-
4.3.6	Junction to Case ¹⁾	R_{thJC}	-	14	-	K/W	measured to exposed pad
4.3.7	Junction to Ambient ¹⁾	R _{thJA}	_	47	-	K/W	
4.3.8			_	141	_	K/W	footprint only ³⁾
4.3.9			-	66	-	K/W	300 mm ² heatsink area on PCB ³⁾
4.3.10	_		-	56	-	K/W	600 mm ² heatsink area on PCB ³⁾

1) not subject to production test, specified by design

2) Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

3) Specified R_{thJA} value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70µm Cu).



5 Block Description and Electrical Characteristics

5.1 Circuit Description

5.1.1 Power On Reset and Reset Output

For an output voltage level $V_Q \ge 1$ V the reset output is hold low. When the level of V_Q reaches the reset threshold V_{RT} , the signal at RO remains low for the power-up reset delay time t_{RD} . The reset function and timing is illustrated in **Figure 4**. The reset reaction time t_{RR} avoids wrong triggering caused by short "glitches" on the V_Q -line. In case of V_Q power down ($V_Q < V_{RT}$ for $t > t_{RR}$) a logic low signal is generated at the pin RO to reset an external microcontroller.

The TLE7279-2GV50 and TLE7279-2EV50 feature an integrated pull-up resistor on the reset output while the TLE7279-2GV33 and TLE7279-2GV26 have an open drain output requiring an external pull-up resistor. When connected to a voltage level of V_{ext} = 5 V, a recommended value for this external resistor is \geq 5.6 k Ω .

But it's also possible calculating its value by using the following formula, based on the reset sink current (Example: external pull-up resistor connected to V_{ext} = 5 V):

 $R_{\text{extmin}} = \Delta V / I_{\text{RO}} = (V_{\text{ext}} - V_{\text{ROmin}}) / I_{\text{RO}} = (5 \text{ V} - 0.25 \text{ V}) / 1.0 \text{ mA} = 4.75 \text{ k}\Omega$

At low output voltage levels V_Q < 1 V the integrated pull-up resistor of the TLE7279-2GV50 is switched off setting the reset output high ohmic.



Figure 4 Reset Function and Timing Diagram



5.1.2 **Early Warning**

The additional sense comparator provides an early warning function: Any voltage (e.g. the input voltage) can be monitored, an undervoltage condition is indicated by setting the comparator's output to low. See Figure 5.



Figure 5 **Early Warning Timing**

The calculation of the voltage divider is easily done since the sense input current can be neglected.

$V_{\text{thHL}} = (R_{\text{SI1}} + R_{\text{SI2}})/R_{\text{SI2}}, V_{\text{SI}}$ low	(1)
$V_{\text{thl H}} = (R_{\text{Sl1}} + R_{\text{Sl2}})/R_{\text{Sl2}}, V_{\text{Sl}}$ high	(2)

 $V_{\text{thLH}} = (R_{\text{SI1}} + R_{\text{SI2}})/R_{\text{SI2}}, V_{\text{SI}}$ high

The sense comparator has a hysteresis of typical 100 mV. This hysteresis of the supervised threshold is multiplied by the resistor dividers amplification $(R_{SI1} + R_{SI2})/R_{SI1}$.

The sense in comparator can also be used for receiving data with a threshold of typical 1.35 V and a hysteresis of 100 mV. Of course also the data signal can be scaled down with a resistive divider as shown above. With a typical delay time of 4 µs receiving data of up to 100 kBaud are possible.



5.2 Electrical Characteristics

Electrical Characteristics

 $V_{\rm I}$ = 13.5 V, $T_{\rm j}$ = -40 °C to +150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
Output	Q						
5.2.1	Output voltage	V _Q	4.90	5.00	5.10	V	TLE7279-2GV50, TLE7279-2EV50 1 mA < I_Q < 180 mA 6 V < V_I < 16 V
5.2.2	Output voltage	V _Q	4.90	5.00	5.10	V	TLE7279-2GV50, TLE7279-2EV50 $I_{\rm Q}$ = 10 mA 6 V < $V_{\rm I}$ < 45 V
5.2.3	Output voltage	V _Q	3.234	3.30	3.366	V	TLE7279-2GV33 1 mA < I_Q < 180 mA 4.5 V < V_I < 16 V
5.2.4	Output voltage	V _Q	3.234	3.30	3.366	V	TLE7279-2GV33 $I_{\rm Q}$ = 10 mA 4.5 V < $V_{\rm I}$ < 45 V
5.2.5	Output voltage	V _Q	2.548	2.60	2.652	V	TLE7279-2GV26 1 mA < I_Q < 180 mA 4.5 V < V_I < 16 V
5.2.6	Output voltage	V _Q	2.548	2.60	2.652	V	TLE7279-2GV26 $I_{\rm Q}$ = 10 mA 4.5 V < $V_{\rm I}$ < 45 V
5.2.7	Output current limitation	IQ	200	_	500	mA	$V_{\rm Q}$ = 2.0 V
			200	-	600	mA	$V_{\rm Q}$ = 0 V
5.2.8	Dropout voltage; $V_{\rm DR} = V_{\rm I} - V_{\rm Q}$	V _{DR}	-	250	500	mV	$I_{\rm Q}$ = 180 mA ¹⁾ TLE7279-2GV50, TLE7279-2EV50
5.2.9	Load regulation	$\Delta V_{\rm Q,Lo}$	-	50	90	mV	1 mA < I _Q < 180 mA
5.2.10	Line regulation	$\Delta V_{\rm Q,Li}$	-	10	50	mV	$I_{\rm Q}$ = 1 mA; 10 V < $V_{\rm I}$ < 32 V
5.2.11	Power-Supply-Ripple-Rejection	PSRR	-	60	-	dB	f _r = 100 Hz; V _r = 0.5 Vpp
5.2.12	Reverse Output Current Clamping	V _{Q,REV}	-	-	5.5	V	$I_{Q,REV}$ = -1 mA; V_{EN} = 0 V
Current	t Consumption						
5.2.13	Quiescent current; $I_q = I_1 - I_Q$	Iq	-	28	36	μA	I _Q = 100 μA; T _j < 80 °C
5.2.14	Quiescent current; Disabled	Iq	-	1	3	μA	V _{EN} = 0 V; T _j < 80 °C
Enable	Input EN		- 1		I	I	
5.2.15	High Level Input Voltage	$V_{\rm EN,H}$	3.0	_	_	V	$V_{\rm O}$ on



Electrical Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V, $T_{\rm j}$ = -40 °C to +150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
5.2.16	Low Level Input Voltage	V _{EN,L}	-	-	0.5	V	$V_{\rm Q}$ = 0.02 V $I_{\rm Q}$ = 5 mA $T_{\rm j}$ < 125 °C
5.2.17			-	-	0.3	V	$V_{\rm Q}$ = 0.02 V $I_{\rm Q}$ = 5 mA
5.2.18	High Level Input current	$I_{\rm EN,H}$	-	3	4	μA	V _{EN} = 5 V
Reset N	Node Bit RM						
5.2.19	High Level Input Voltage	V _{RM,H}	4.00	-	-	V	TLE7279-2GV50, TLE7279-2EV50
5.2.20			2.65	-	-	V	TLE7279-2GV33
5.2.21			2.30	-	-	V	TLE7279-2GV26
5.2.22	Low Level Input Voltage	$V_{\rm RM,L}$	-	-	0.80	V	-
Input V	oltage Sense						
5.2.23	Sense threshold high	V _{SIH}	1.10	1.16	1.22	V	V _{SI} increasing (see Figure 4)
5.2.24	Sense threshold low	V _{SIL}	1.06	1.12	1.18	V	V _{SI} decreasing (see Figure 4)
5.2.25	Sense input switching hysteresis	$V_{\rm SIHYST}$	25	-	75	mV	$V_{\rm SIHYST}$ = $V_{\rm SIH}$ - $V_{\rm SIL}$
5.2.26	Sense output low current	I _{SOL}	-	-	1.1	mA	$V_{\rm SI}$ < 1.01 V; $V_{\rm I}$ > 4.5 V; EN = High; $V_{\rm SOL}$ < 0.4 V
5.2.27	Sense output low voltage	V _{so}	-	0.15	0.25	V	$V_{\rm SI}$ < 1.01 V; $V_{\rm I}$ > 4.5 V; EN = High; $I_{\rm SO}$ < 200 μ A
5.2.28	Sense high voltage	V _{SOH}	4.5	-	-	V	TLE7279-2GV50, TLE7279-2EV50
5.2.29	Sense high leakage current	I _{SOLK}	-	-	1	μA	TLE7279-2GV33 TLE7279-2GV26
5.2.30	Integrated sense pull-up resistor	R _{SO}	10	20	40	kΩ	TLE7279-2GV50, TLE7279-2EV50 internally connected to $V_{\rm Q}$
5.2.31	Sense input current	$I_{\rm SI}$	-1	0.1	1	μA	$V_{\rm SI}$ = 5 V
5.2.32	Sense reaction time	t _{pd SO}	_	4.0	_	μs	_



Electrical Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V, $T_{\rm j}$ = -40 °C to +150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
Reset (Dutput RO		L				
5.2.33	Output Undervoltage Reset Switching Threshold	V _{RT}	4.50	4.60	4.70	V	TLE7279-2GV50, TLE7279-2EV50 $V_{\rm Q}$ decreasing
5.2.34			3.00	3.07	3.13	V	TLE7279-2GV33 ²⁾ $V_{\rm Q}$ decreasing
5.2.35			2.35	2.38	2.45	V	TLE7279-2GV26 ²⁾ $V_{\rm Q}$ decreasing
5.2.36	Input Voltage Reset Switching Threshold	V _{RT_VI}	-	3.9	4.0	V	TLE7279-2GV26 ²⁾ TLE7279-2GV33 ²⁾
							$V_{\rm Q} > V_{\rm RT},$ $V_{\rm I}$ decreasing
5.2.37	Reset Hysteresis	V_{RH}	-	45	-	mV	TLE7279-2GV26
5.2.38	_		-	60	-	mV	TLE7279-2GV33
5.2.39	_		-	90	-	mV	TLE7279-2GV50, TLE7279-2EV50
	Maximum Reset Sink Current	$I_{\rm RO,max}$	1.75	-	-	mA	TLE7279-2GV50, TLE7279-2EV50
							$V_{\rm Q}$ = 4.5 V, $V_{\rm RO}$ = 0.25 V
5.2.41			1.3	_	-	mA	TLE7279-2GV33 $V_{\rm Q}$ = 3.0 V, $V_{\rm RO}$ = 0.25 V
5.2.42			1.0	-	-	mA	TLE7279-2GV26 $V_{\rm Q}$ = 2.35 V, $V_{\rm RO}$ = 0.25 V
5.2.43	Reset output low voltage	V _{ROL}	-	0.15	0.25	V	V _Q ≥1 V; I _{RO} < 200 μA
5.2.44	Reset high voltage	V _{ROH}	4.5	-	-	V	TLE7279-2GV50, TLE7279-2EV50
5.2.45	Reset high leakage current	I _{ROLK}	-	-	1	μA	TLE7279-2GV33 TLE7279-2GV26
5.2.46	Integrated reset pull-up resistor	R _{RO}	10	20	40	kΩ	TLE7279-2GV50, TLE7279-2EV50
							internally connected to $V_{\rm Q}$



Electrical Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V, $T_{\rm j}$ = -40 °C to +150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
5.2.47	Power-on reset delay time	T _{RD}	12.8	16.0	19.2	ms	fast reset timing RM = Low
			25.6	32.0	38.4	ms	slow reset timing RM = High
5.2.48	Reset Reaction Time	T _{RR}	_	4	12	μs	_3)

1) measured when the output voltage has dropped 100 mV from the nominal value obtained at $V_{\rm I}$ = 13.5 V

2) reset output triggered when output voltage $V_{\rm Q}$ is lower than output voltage reset switching threshold $V_{\rm RT}$ or is also triggered, when Input Voltage is decreasing to $V_{\rm I}$ < 4.0 V and $V_{\rm Q}$ > $V_{\rm RT}$

3) not subject to production test, specified by design



Typical Performance Characteristics

Current Consumption I_q versus Junction Temperature T_j (EN=ON)



Current Consumption I_q versus Input Voltage V_1 at $T_i=25^{\circ}C$ (EN=ON)



Current Consumption I_q versus Output Current I_Q (EN=ON)



Current Consumption I_q versus Input Voltage V_1 at T_1 =-40°C (EN=ON)









Power Supply Ripple Rejection PSRR



Load Regulation dV_q versus Output Current Change dI_q



Load Regulation dV_{Q} versus Output Current Change dI_{Q}





Line Regulation $\mathrm{d}V_{\mathrm{Q}}$ versus Input Voltage Change $\mathrm{d}V_{\mathrm{I}}$



Line Regulation dV_Q versus Input Voltage Change dV_I



Line Regulation dV_{Q} versus Input Voltage Change dV_{I}



Enable Input Current $I_{\rm EN}$ versus Enable Input Voltage $V_{\rm EN}$









Reset Threshold $V_{\rm RT}$ versus Junction Temperature $T_{\rm i}$ (5V-Version)







Reset Hysteresis versus Junction Temperature T_i (5V-Version)







Reset Threshold $V_{\rm RT}$ versus Junction Temperature $T_{\rm j}$ (3.3V-Version)

Reset Threshold $V_{\rm RT}$ versus Junction Temperature $T_{\rm i}$ (2.6V-Version)



Reset Hysteresis versus Junction Temperature T_i (3.3V-Version)



Reset Hysteresis versus Junction Temperature T_i (2.6V-Version)





Typical Performance Characteristics (cont'd) Reset Delay $t_{\rm RD}$ Time versus Junction Temperature $T_{\rm i}$



Reset Output Sink Current $I_{\rm RO}$ versus Junction Temperature $T_{\rm i}$





Region of Stability $ESR(C_Q)$ versus Output Current I_Q





Package Outlines

6 Package Outlines





TLE7279-2

Package Outlines



Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.



7 Revision History

Revision	Date	Changes
1.2	2009-05-08	2.6V version, 5V version in PG-SSOP-14 package and all related description added:
		In "Features" on Page 2 "or 2.6V" added
		In "Features" on Page 2 package drawing for PG-DSO-14 updated, package drawing for PG-SSOP-14 added
		In "Overview" on Page 2 in table at the bottom types "TLE7278-2GV26" and TLE7279-2EV50" added
		In Table 2.2 "Pin Definitions and Functions (PG-DSO-14)" on Page 3 in description for Pin 1 and Pin 7 ", TLE7273-2GV26" added
		In "Pin Assignment (PG-DSO-14)" on Page 3 "(PG-DSO-14)" added; In "Pin Definitions and Functions (PG-DSO-14)" on Page 3 "(PG-DSO-14)" added;
		In Table 2.2 "Pin Definitions and Functions (PG-DSO-14)" on Page 3 in description for pin 1 "; leave open if Reset is not needed" added
		"Pin Assignment (PG-SSOP-14 Exposed Pad)" on Page 4 and "Pin Definitions and Functions (PG-SSOP-14 Exposed Pad)" on Page 4 added
		In "Functional Range" on Page 7 Item 4.2.3 added, in Item 4.2.1 ", TLE7279- 2EV50" added
		In Table 4.3 "Thermal Resistance" on Page 7 above Item 4.3.1 line with "Package PG-DSO-14" and values for PG-SSOP-14 package added: Item 4.3.6, Item 4.3.7, Item 4.3.8, Item 4.3.9, and Item 4.3.10 added
		In "Power On Reset and Reset Output" on Page 8 "and TLE7279-2EV50" in description added
		In "Electrical Characteristics" on Page 10 all specific items for 2.6V version added: Item 5.2.5, Item 5.2.6, Item 5.2.21, Item 5.2.35, Item 5.2.37 and Item 5.2.42 added; In Item 5.2.29, Item 5.2.36 and Item 5.2.45 conditions for 2.6V version added; In Item 5.2.1, Item 5.2.2, Item 5.2.8, Item 5.2.19, Item 5.2.28, Item 5.2.30, Item 5.2.33, Item 5.2.39, Item 5.2.40, Item 5.2.44 and Item 5.2.46 in conditions ", TLE7279-2EV50" added
		In "Typical Performance Characteristics" on Page 14 Graphs "Reset Threshold VRT versus Junction Temperature Tj (3.3V-Version)" on Page 18, "Reset Hysteresis versus Junction Temperature Tj (3.3V-Version)" on Page 18, "Reset Threshold VRT versus Junction Temperature Tj (2.6V- Version)" on Page 18 and "Reset Hysteresis versus Junction Temperature Tj (2.6V-Version)" on Page 18 added
		In "Package Outlines" on Page 20 Outlines for PG-SSOP-14 package added: Figure 7
1.1	2008-07-25	3.3V version and all related description added:
		In "Features" on Page 2" 3.3V" added
		In "Overview" on Page 2 in table at the bottom type "TLE7273-2GV33" added
		In "Pin Definitions and Functions (PG-DSO-14)" on Page 3 in description for Pin 1 and Pin 7 "TLE7273-2GV33: open drain output;" added
		In "Functional Range" on Page 7 Item 4.2.2 added



Revision History

Revision	Date	Changes
		In "Power On Reset and Reset Output" on Page 8 description for dimensioning external pull-up resistor at RO added
		In "Electrical Characteristics" on Page 10 all specific Items for 3.3V version added: Item 5.2.3, Item 5.2.4, Item 5.2.20, Item 5.2.29, Item 5.2.34, Item 5.2.36, Item 5.2.38, Item 5.2.41 and Item 5.2.45 added
1.0	2008-04-10	final version data sheet

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